Potential sputtering of ionic species from rare gas solids by multiply charged ion impact

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Abstract. The interaction of low-energy multiply charged Ar⁺ⁿ⁺ (q ≤ 7) ions with a solid Ne surface is experimentally studied. Desorption of very large cluster ions Ne⁺ⁿ (n > 100) is observed. The size distribution of smaller (n = 1 ∼ 3) cluster ions depends strongly on the charge state of the incident ion, whereas that of larger (n > 7) cluster ions exhibits no dependence on the charge state, indicating that desorption of large cluster ions is due to kinetic sputtering. The potential sputtering yield is estimated by analyzing the size distribution of the desorbed cluster ions. The results suggest that the ion desorption mechanism, which is known as desorption induced by electronic transitions, can also be applied to the present results.

1. Introduction

Rare-gas solids (RGS) are interesting materials for investigating the dynamic processes of desorption induced by electronic transitions (DIET) because of their simplicity and because their electronic structures resemble those of isolated atoms. Furthermore, they have several characteristics that differ greatly from those of other materials, including low cohesive energies (e.g., 0.02 eV/atom for Ne), large band-gap energies (e.g., 21.6 eV for Ne), and long exciton diffusion lengths (e.g., ~ 200 nm for Ne), etc. [1]

Desorption of atoms and ions by low-energy electron impact, known as electron-stimulated desorption (ESD), or by VUV photon irradiation, known as photon-stimulated desorption (PSD), from the surfaces of RGS has been extensively studied over the past two decades [2–4]. The creation of excitons and ions plays an important role in the desorption of neutral atoms, whereas the formation of an electronically excited ion or a doubly charged ion is essential for the desorption of singly charged ions [5]. This is also true for the desorption of doubly charged ions, where a core-excited ion or a triply charged ion can be the initial state that leads to desorption [6].

Sputtering from RGS by singly charged keV ion impact has been investigated by various groups [7–13], and a kinetically induced sputtering mechanism has been discussed in detail.

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Here, we report for the first time the potential sputtering of ionic species from the surface of solid Ne by low-energy multiply charged Ar ion impact, and we report the potential sputtering yield.

2. Experimental

Multiply charged ions (Ar\(^{q+}\), \(q \leq 7\)) are generated by an electron cyclotron resonance ion source (NANOGAN). Extracted ions are mass-selected by an analyzing magnet and are focused onto the sample surface at the center of a main chamber (see Fig. 1). The main chamber is evacuated by a series of turbomolecular pumps and a Ti-getter pump, resulting in a pressure of about 8 \(\times 10^{-9}\) Pa. Rare-gas solids are condensed onto a polycrystalline Cu substrate cooled to 4.5 K by a mechanical cryostat. The sample film is condensed onto the Cu disk by filling the chamber with gaseous Ne to a pressure of \(10^{-6} \sim 10^{-4}\) Pa. The film thickness was estimated from the exposure by assuming the condensation coefficient to be unity.

Sputtered ionic species are detected by a microchannel plate (MCP) detector or a quadrupole mass spectrometer (QMS; MSQ-400, ULVAC) in pulse-counting mode. Time-of-flight (TOF) mass spectra are measured using the MCP detector by pulsing the incident ion beam, while a DC beam is used for obtaining mass spectra using the QMS. In the TOF measurements, a bias voltage of +100 V is applied to the sample substrate to accelerate the sputtered ions. When using the QMS, the sample is grounded and the ionizer of the QMS is turned off. The incident ion beam current can be measured to a higher accuracy using the QMS than using a pulsed ion beam.
with the MCP detector, although the measurement range is restricted to $M/q \leq 400$ with the QMS used in this study.

As the desorption yield is very large for solid Ne [14], a low incident ion beam current (less than 1 nA) is used to minimize the change in sample thickness during measurement. The sample is evaporated and redeposited after each measurement.

3. Results and Discussion

Figure 2 shows TOF spectra of ions desorbed by 2.7 keV Ar$^{3+}$ ion impact. The figure shows that the main desorbing species are the cluster ions Ne$_n^+$ ($n$: cluster size) and that very large clusters ($n > 100$) are present (Fig. 2(b)). Clear steps are observed (i.e., magic numbers at $n = 14$ and 21), as also reported in supersonic cluster beam experiments [15]. The magic number $n = 14$ is attributed to an icosahedral structure with a dimer ion at its core [16]. Similar spectra have been observed for low-energy Ne$^{q+}$ impact but not for excitation by 100 eV electron impact ($n_{\text{max}} \sim 5$). Desorption of such large cluster ions is not detected from the surface of solid Ar ($n_{\text{max}} \sim 20$). A detailed discussion of the growth and desorption mechanism for such large cluster ions will be published elsewhere [17].

Figure 3 shows the mass spectra of desorbed cluster ions from solid Ne by 1 keV Ar$^q+$ ($q = 1, 3, \text{ and } 6$) ion impact measured by QMS. The vertical axis is the number of detected ions normalized by the number of incident ions (i.e., $I_i/q$). It clearly shows that the intensities of the smaller cluster ions ($n = 1 \sim 3$) depend strongly on the charge state of the incident ions. The peak area for each cluster size is plotted in Fig. 4 for $q = 1, 3, 4, 6, \text{ and } 7$, clearly demonstrating the charge state dependence of the size distribution. The figure shows that the desorption yield of larger clusters ($n > 7$) does not depend on the charge state, indicating that the desorption mechanism of large cluster ions is kinetic sputtering.

Considering that the potential energy of Ar$^+$ (15.76 eV) is less than the creation energies of an exciton (17.1 eV) and an ion (21.6 eV) in solid Ne [1], we assume that
Figure 3. Mass spectra of desorbed cluster ions by 1 keV Ar\textsuperscript{q+} (q = 1, 3, and 6) ion impact measured by the QMS. The vertical axis is the number of detected ions normalized by the number of incident ions.

Figure 4. Dependence of the size distribution on the charge state of the incident ions. Incident energy of the ion is 1 keV for all charge states. See text for details.
only kinetic sputtering occurs in the desorption of ionic species by Ar$^+$ ion impact. To estimate the potential sputtering yield (PSY), the contribution of kinetic sputtering (i.e., the sum of the peak areas of Ar$^+$ impact; shaded area in Fig. 4) is subtracted from the size distribution of $q \geq 2$. The results are plotted in Fig. 5 for incident ion energies $E_i$ of 500 eV and 1 keV. The vertical axis in Fig. 4 corresponds to the number of charges (not atoms) per incident ion in arbitrary units. This figure shows that the slopes the incident energies of $E_i = 500$ eV and 1 keV are almost identical, and that PSY increases linearly with the potential energy of the incident ion up to the highest charge state ($q = 7$) used in this study. These observations suggest that the DIET mechanism of the ion desorption confirmed by the ESD and PSD experiments for RGS can also be applied to the ion-induced potential sputtering process. This mechanism resembles the defect-mediated desorption model [18, 19] in the sense that an excited atom or an ion can initiate the desorption.

The $x$-axis intercept (i.e., the threshold energy of the potential sputtering) is found to be $\sim 40$ eV from the result of $E_i = 500$ eV. This energy is approximately twice the band-gap energy of solid Ne. The creation of two adjacent ions may lead to desorption of an ion due to Coulomb repulsion, although such a process has not been observed in photon-stimulated ion desorption experiments for solid Ar and solid Kr [5]. Another possibility is that a doubly excited atom is created in solid Ne, which desorbs from the surface, autoionizes, and is detected as Ne$^+$[20].

There is a difference between the two lines in Fig. 5, suggesting that the contribution of kinetic sputtering may not have been completely subtracted from the present results, even for $E_i = 500$ eV. The threshold energy obtained in the present study is the minimum value, and experiments with a lower incident ion energy are needed to determine the true threshold energy.
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